

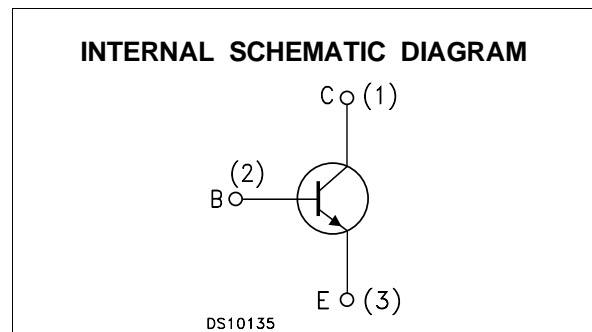
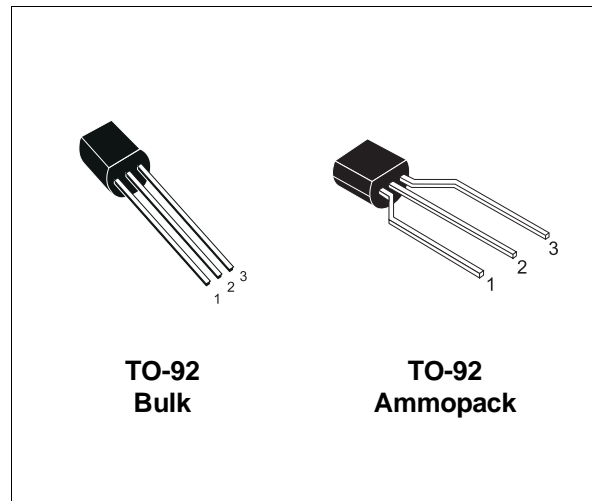
## SMALL SIGNAL NPN TRANSISTORS

Ordering Code	Marking	Package / Shipment
BC547B	BC547B	TO-92 / Bulk
BC547B-AP	BC547B	TO-92 / Ammopack
BC547C	BC547C	TO-92 / Bulk
BC547C-AP	BC547C	TO-92 / Ammopack

- SILICON EPITAXIAL PLANAR NPN TRANSISTORS
- TO-92 PACKAGE SUITABLE FOR THROUGH-HOLE PCB ASSEMBLY
- BC547B - THE PNP COMPLEMENTARY TYPE IS BC557B
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### APPLICATIONS

- WELL SUITABLE FOR TV AND HOME APPLIANCE EQUIPMENT
- SMALL LOAD SWITCH TRANSISTORS WITH HIGH GAIN AND LOW SATURATION VOLTAGE



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage ( $I_E = 0$ )	50	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )	45	V
$V_{EBO}$	Emitter-Base Voltage ( $I_C = 0$ )	6	V
$I_C$	Collector Current	100	mA
$I_{CM}$	Collector Peak Current ( $t_p < 5$ ms)	200	mA
$P_{tot}$	Total Dissipation at $T_C = 25$ °C	500	mW
$T_{stg}$	Storage Temperature	-65 to 150	°C
$T_j$	Max. Operating Junction Temperature	150	°C

## BC547B / BC547C

### THERMAL DATA

R <sub>thj-amb</sub> •	Thermal Resistance Junction-Ambient	Max	250	°C/W
R <sub>thj-Case</sub> •	Thermal Resistance Junction-Case	Max	83.3	°C/W

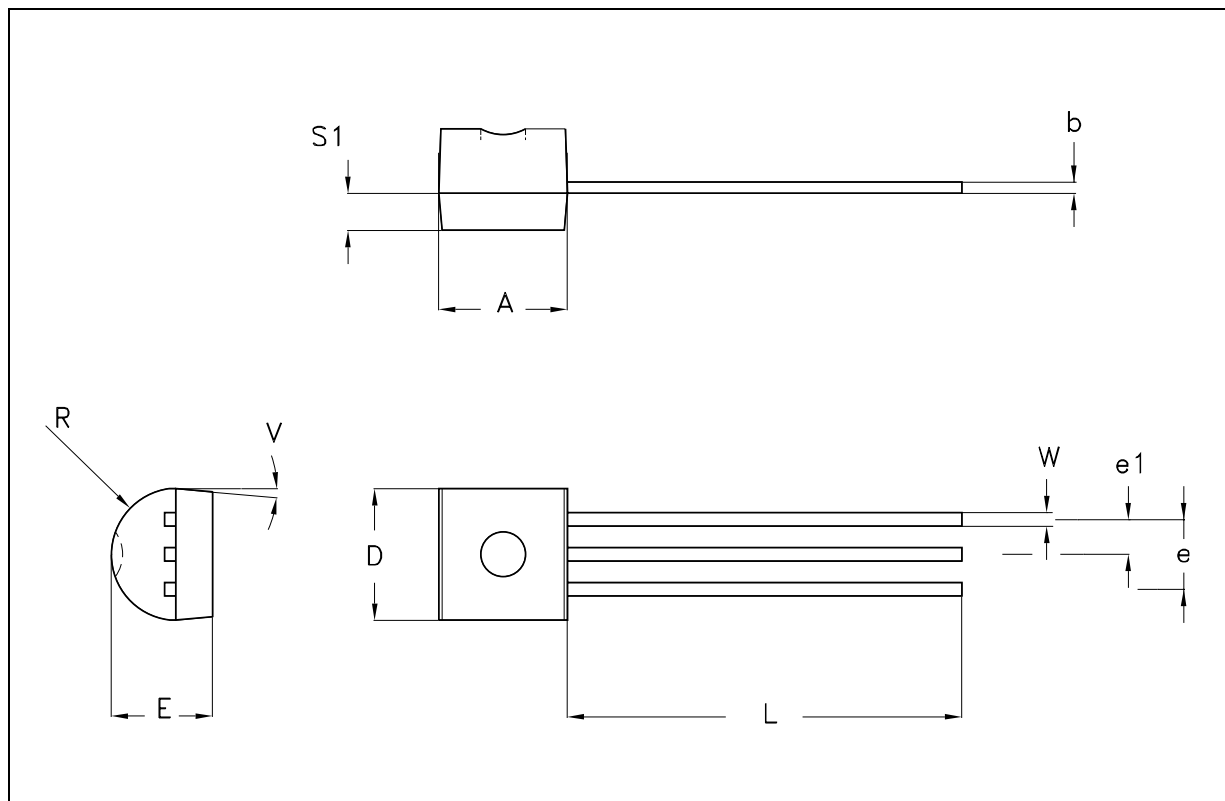
### ELECTRICAL CHARACTERISTICS (T<sub>case</sub> = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I <sub>CBO</sub>	Collector Cut-off Current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 30 V V <sub>CB</sub> = 30 V      T <sub>C</sub> = 150 °C			15 5	nA μA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V			100	nA
V <sub>(BR)CEO</sub> *	Collector-Emitter Breakdown Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10 mA	45			V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 10 mA      I <sub>B</sub> = 0.5 mA I <sub>C</sub> = 100 mA      I <sub>B</sub> = 5 mA		0.09 0.2	0.25 0.6	V V
V <sub>BE(sat)</sub> *	Base-Emitter Saturation Voltage	I <sub>C</sub> = 10 mA      I <sub>B</sub> = 0.5 mA I <sub>C</sub> = 100 mA      I <sub>B</sub> = 5 mA		0.7 0.9		V V
V <sub>BE(on)</sub> *	Base-Emitter On Voltage	I <sub>C</sub> = 2 mA      V <sub>CE</sub> = 5 V I <sub>C</sub> = 10 mA      V <sub>CE</sub> = 5 V	0.58	0.66	0.7 0.77	V V
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 2 mA      V <sub>CE</sub> = 5 V for <b>BC547B</b> for <b>BC547C</b>	200 420		450 800	
f <sub>T</sub>	Transition Frequency	I <sub>C</sub> = 10 mA    V <sub>CE</sub> = 5 V    f = 100MHz	100			MHz
C <sub>CBO</sub>	Collector-Base Capacitance	I <sub>E</sub> = 0      V <sub>CB</sub> = 10 V    f = 1 MHz		1.5		pF
C <sub>EBO</sub>	Emitter-Base Capacitance	I <sub>C</sub> = 0      V <sub>EB</sub> = 0.5 V    f = 1 MHz		11		pF
NF	Noise Figure	V <sub>CE</sub> = 5 V    I <sub>C</sub> = 200 μA    f = 1KHz Δf = 200 Hz    R <sub>G</sub> = 2 KΩ		2	10	dB

\* Pulsed: Pulse duration = 300 μs, duty cycle ≤ 2 %

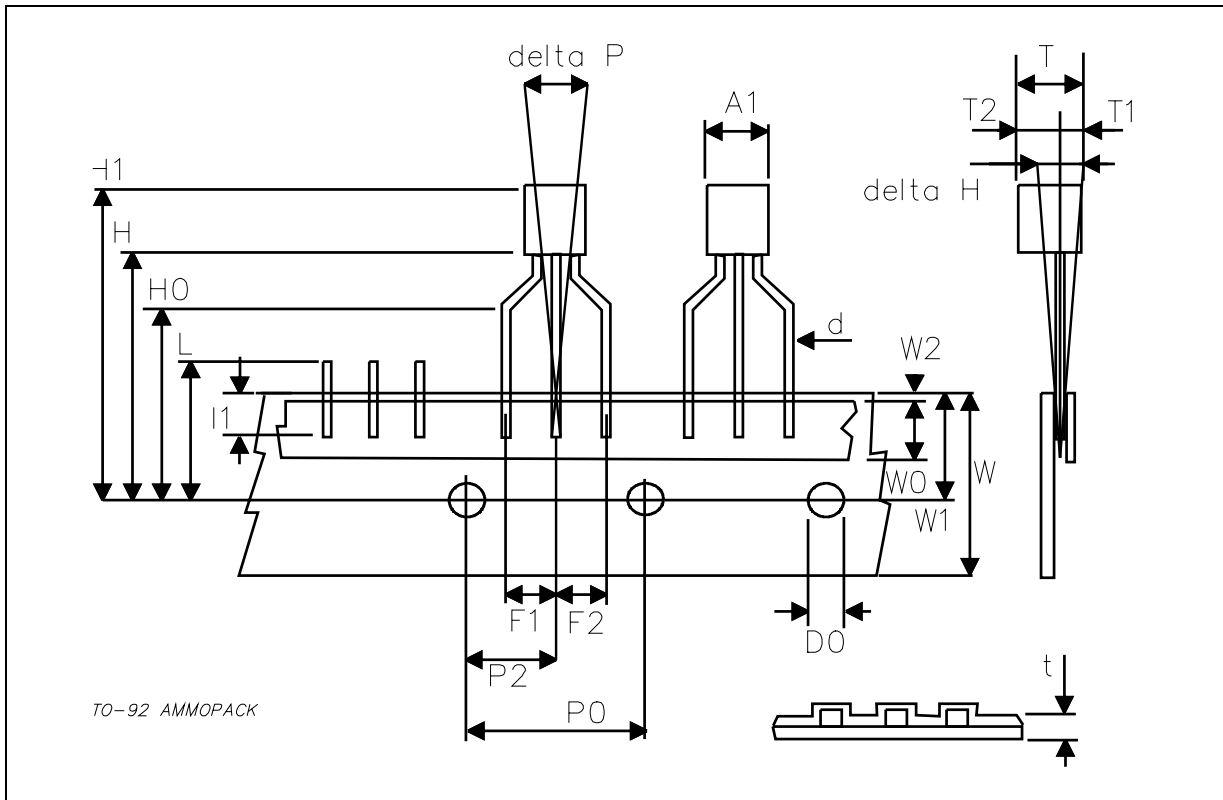
## TO-92 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.32		4.95	0.170		0.195
b	0.36		0.51	0.014		0.020
D	4.45		4.95	0.175		0.194
E	3.30		3.94	0.130		0.155
e	2.41		2.67	0.095		0.105
e1	1.14		1.40	0.045		0.055
L	12.70		15.49	0.500		0.609
R	2.16		2.41	0.085		0.094
S1	1.14		1.52	0.045		0.059
W	0.41		0.56	0.016		0.022
V	4 degree		6 degree	4 degree		6 degree



**TO-92 AMMOPACK SHIPMENT (Suffix"-AP") MECHANICAL DATA**

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A1			4.80			0.189
T			3.80			0.150
T1			1.60			0.063
T2			2.30			0.091
d			0.48			0.019
P0	12.50	12.70	12.90	0.492	0.500	0.508
P2	5.65	6.35	7.05	0.222	0.250	0.278
F1,F2	2.44	2.54	2.94	0.096	0.100	0.116
delta H	-2.00		2.00	-0.079		0.079
W	17.50	18.00	19.00	0.689	0.709	0.748
W0	5.70	6.00	6.30	0.224	0.236	0.248
W1	8.50	9.00	9.25	0.335	0.354	0.364
W2			0.50			0.020
H	18.50		20.50	0.728		0.807
H0	15.50	16.00	16.50	0.610	0.630	0.650
H1			25.00			0.984
D0	3.80	4.00	4.20	0.150	0.157	0.165
t			0.90			0.035
L			11.00			0.433
I1	3.00			0.118		
delta P	-1.00		1.00	-0.039		0.039



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